# Ultra Large band Silicon Capacitor ULSC 0402 47nF BV30



Rev. 3.00

### General description

ULSC Capacitor targets Optical communication system such as ROSA/TOSA, SONET and all optoelectronics as well as High speed data system or products.

The ULSC is suitable for DC blocking, feedback, coupling and bypassing applications in all broadband optoelectronics and High-speed data system.

The unique technology of integrated passive device in silicon, developed by Murata Integrated Passive Solutions, offers unique performances with low insertion loss, low reflection and phase stability from 34 KHz to 20 GHz.

These BroadBand MOS Silicon Capacitors (ULSC) have been developed in a semiconductor process, in order to combine ultra-deep trench MOS capacitors for high capacitance value of 47nF in a 0402 [1,2x0,7mm] case.

The ULSC capacitor provides very high stability of the capacitance over temperature, voltage variation as well as a very high reliability.

ULSC capacitors have an extended operating temperature ranging from -55 to 150°C, with very low capacitance change over temperature.

<u>Assembly:</u> Suitable for surface mounted application on rigid PCB, ceramic substrate, FR4 (laminate) or flex platforms.

### **Bump finishing: ENIG**

Copper pads optional for embedding version and SAC305 type 6 for pre-bumping version, as an optional finishing.

### Key features

- Broadband performance to 20 GHz
- Resonance free
- Phase stability
- Insertion low < 0.4dB Typ. up to 20 GHz</li>
- Ultra-high stability of capacitance value:
  - Temperature +70ppm/K (-55 °C to +150 °C)
  - Voltage <-0.1%/Volts</li>
  - o Negligible capacitance loss through ageing

- Low profile: 400μm, 100 μm on request
- Break down voltage: 30V
- Low leakage current < 100pA
- High reliability
- High operating temperature (up to 150 °C)
- Compatible with high temperature cycling during manufacturing operations (exceeding 300 °C)
- Compatible with almost EIA 0402 footprint

### Key applications

- ROSA/TOSA
- SONET
- · High speed digital logic

- Microwave/millimetre system
- High volumetric efficiency (i.e. capacitance per unit)
- · Broadband test equipment



## Functional diagram

The next figure provides implementation set-up diagram.

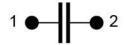


Figure 1 Block Diagram

### Electrical performances

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
С	Capacitance value	@+25°C		47	-	nF
$\Delta C_P$	Capacitance tolerance (1)	@+25°C	-15	-	+15	%
T <sub>OP</sub>	Operating temperature		-55	20	150	°C
T <sub>STG</sub>	Storage temperature (2)		-70	-	165	°C
$\Delta C_{T}$	Capacitance temperature variation	-55 °C to 150 °C	-	70	-	ppm/K
RV <sub>DC</sub>	Rated voltage (3)		)-)	-	16 <sup>(4)</sup> 14.7 <sup>(5)</sup>	$V_{DC}$
BV	Break down voltage	@+25°C	30	-	-	V
$\Delta C_{RVDC}$	Capacitance voltage variation	From 0 V to RV <sub>DC</sub> , @+25°C	-	-	-0.1	%/V <sub>DC</sub>
IR	Insulation resistor	@RV <sub>DC</sub> , +25°C, 120s	-	10	-	GΩ
ESR	Equivalent Serial Resistance	quivalent Serial Resistance @+25°C, shunt mode		250	400	mΩ
ESL	Equivalent Serial Inductance	@+25°C, SRF shunt mode	-	180	-	рН
Fc-3dB	Cut-off frequency at 3dB		-	34	40	kHz
IL	Insertion loss	@ 20 GHz	-	0.4	-	dB
RL	Return loss	Up to 20 GHz	12	-	-	dB
ESD	HBM stress (6)	JS-001-2017	2	_	-	kV

Table 1 - Electrical performances

<sup>(1):</sup> other tolerance available upon request

<sup>(2):</sup> without packaging

<sup>(3):</sup> Lifetime is voltage and temperature dependent, please refer to application note 'Lifetime of 3D capacitors'

<sup>(4): 10</sup> years of intrinsic lifetime prediction at 100°C continuous operation

<sup>(5): 10</sup> years of intrinsic lifetime prediction at 150°C continuous operation

<sup>(6):</sup> please refer to application note 'ESD Challenge in 3D Murata Integrated Passive technology'

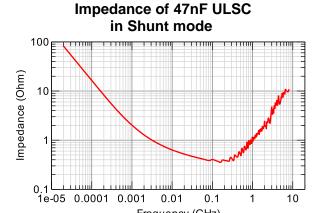


Figure 2 - 47nF ULSC Measured results (module of Z-parameters)

# Module S-parameters of 47nF ULSC in transmission mode

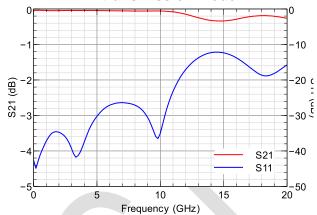


Figure 3 - 47nF ULSC measurement results (module of Sparameters)

# Schematic of 47nF ULSC in transmission mode

0.01

Frequency (GHz)

0.1

10

# ULSC724.547 50Ω

# 10-mil Rogers 4350B.

Microstrip mode – line width = 0.551mm and gap = 0.246 mm. (nominal 50 ohm characteristic impedance).

Figure 4 - 47nF ULSC measurement schematic

# Example of 0402 surface mounted

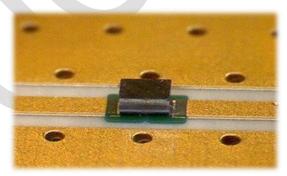


Figure 5 - micro picture of ULSC mounted on board in coplanar mode

# Pinning definition

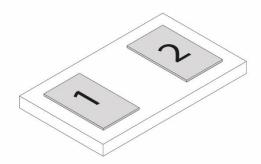


Figure 5 Pinning definition

pin#	Symbol	Coordinates X / Y
1	Signal	-350.0 / 0.0
2	Signal	350.0 / 0.0

Table 2 - Pining description. Reference (0,0) located at the centre of the die.

# **Ordering Information**

Murata Integrated Passive Devices delivers products with AQL level II (0.65). Tighter quality levels are available upon request.

Part number	Package				
rait iluilibei	Packaging	Finishing	Description		
935155724547-F1N	6" film frame carrier <sup>(1)</sup>	ENIG <sup>(2)</sup>	ULSC 0402 - 47nF - 2 pads - 1.2 x 0.7mm x 0.4mm		
935155724547-T3N	T&R 1 000units <sup>(3)</sup>	ENIG <sup>(2)</sup>	ULSC 0402 - 47nF - 2 pads - 1.2 x 0.7mm x 0.4mm		
935156724547-F1N	6" film frame carrier <sup>(1)</sup>	ENIG <sup>(2)</sup>	ULSC 0402 - 47nF - 2 pads - 1.2 x 0.7mm x 0.1mm		
935156724547-T3N	T&R 1 000units <sup>(3)</sup>	ENIG <sup>(2)</sup>	ULSC 0402 - 47nF - 2 pads - 1.2 x 0.7mm x 0.1mm		

Table 3 - Packaging and ordering information

- Other film frame carrier are possible on request
- ENIG : Min 0.1µm Au / 5µm Ni missing capacitors can reach 0.5%

Product Name	Die Name	Description
ULSC724.547	UJ0402547	ULSC 47nF / 0402 / BV30 - 2 pads - 1.2 x 0.7 x 0.40 mm
ULSC724.547	UJ0402547	ULSC 47nF / 0402 / BV30- 2 pads - 1.2 x 0.7 x 0.10 mm

Table 4 - Die information



### Pad Metallization

This surface mounted Silicon Capacitor is delivered as standard with NiAu (ENIG (0.1µm Au / 5µm Ni)).

Other Metallization, such as Copper, Thick Gold or Aluminum pads are possible on request.

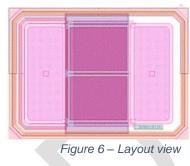
Silicon dies are not sensitive to humidity, please refer to applications notes 'Assembly Notes' section 'Handling precautions and storage'.

# Material regulation

This product is RoHS compliant at the time of publication. For further information about regulation compliancy, please ask your sales representative.

### Package outline

The product is delivered as a bare silicon die.



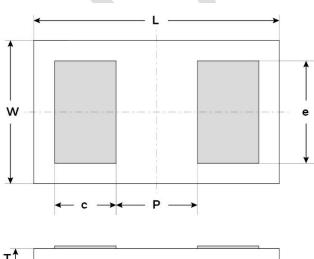


Figure 6: Package outline drawing



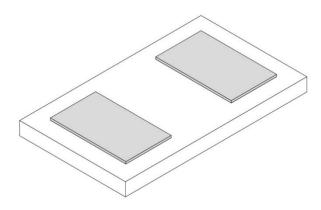


Figure 7 - Package isometric view

L (mm)	W (mm)	T (mm)	c (mm)	P (mm)	e (mm)
1.2 <sub>±0.04</sub>	0.7 <sub>±0.04</sub>	0.40 or 0.10 ±0.01	0.30	0.40	0.50

Table 5 - Dimensions and tolerances





### Assembly

The attachment techniques recommended by Murata on the customer's substrates are fully detailed in specific documents available on our website. To assure the correct use and proper functioning of Murata capacitors please download the assembly instructions on <a href="https://www.murata.com/en-us/products/capacitor/siliconcapacitors">https://www.murata.com/en-us/products/capacitor/siliconcapacitors</a> and read them carefully.



Figure 6 Scan this QR Code to access the Murata Silicon Capacitor web page

# Packaging format

Please refer to application note 'Products Storage Conditions and Shelf Life'.

### Tape and Reel:

Dies are flipped in the tape cavity (bump down) with die ID located near the driving holes of the tape.

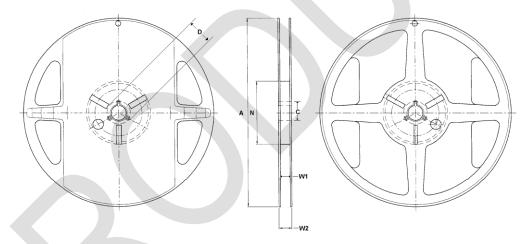


Figure 7 - Reel drawing

Tape Width	Diameter A	С	D	Hub N	W1	W2
8	178 (7 inches)	13.5	20.2	60	9.3	11.5

Table 6 – Reel dimensions (mm)

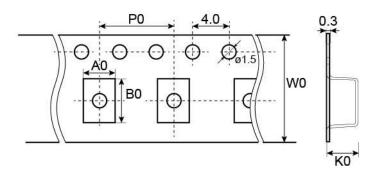


Figure 8 - Tape drawing

Cavity dimensions			Carrier tape	Carrier tape	Reel	
Ao	Во	Ko	width W0	pitch P0	Capacity	
0.92	1.31	0.56	8	4	1 000	

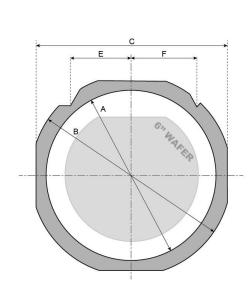
Table 7 - Tape dimensions (mm)



# **Film Frame Carrier:**

With UV curable dicing tape (UV performed).

Good dies are identified using the SINF electronic mapping format. No ink is added on wafer to label other dies.



A B

Figure 9 FF070 Frame with a 6" wafer

Figure 10 FF108 Frame with a 6" wafer

Frame Reference	Frame Style	Inside diameter A	Outside diameter B	Width C	Thickness	Pin location E	Pin location F
FF070 <sup>(1)</sup>	DTF-2-6-1	7.638"	8.976"	8.346"	0.048"	2.370"	2.5"
FF108 <sup>(1)</sup>	DTF-2-8-1	9.842"	11.653"	10.866"	0.048"	2.381"	2.5"

Table 8 - Frame dimensions (inches)

(1) or equivalent



# Expander grip ring 6" diameter:

With UV curable dicing tape (UV performed)

Good dies are identified using the SINF electronic mapping format. No ink is added on wafer to label other dies.

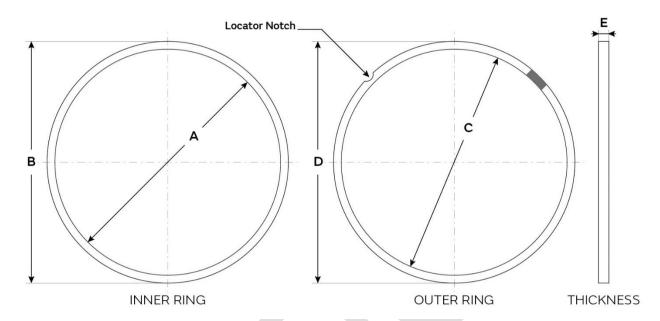


Figure 11 - Grip Ring drawing

Grip Ring Style	Α	В	С	D	Е	Locator Notch
GRP-2620-6 (1)	7.670"	7.973"	7.975"	8.280"	0.236"	None

Table 9 - Frame dimensions (inches)

(1) or equivalent





### **Definitions**

Data sheet status

**Objective specification:** This data sheet contains target or goal specifications for product development.

**Preliminary specification:** This data sheet contains preliminary data; supplementary data may be published later.

**Product specification:** This data sheet contains final product specifications.

Limiting values

Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those given in the Electrical performances sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

### **Revision history**

Revision	Date	Description	Author
Release 1.0	2014 February 18 <sup>th</sup>	Objective specification	LDU
Release 1.7	2018 April 19th	Transfer FBC 0001	MSI / OGA
Release 3.00	2021 May 21st		CGU, LLR, DDE, SCA, DYO, OGA

### Disclaimer / Life support applications

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